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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	STM8
Core Size	8-Bit
Speed	16MHz
Connectivity	I²C, IrDA, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, IR, POR, PWM, WDT
Number of I/O	41
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 25x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8l151c8t6

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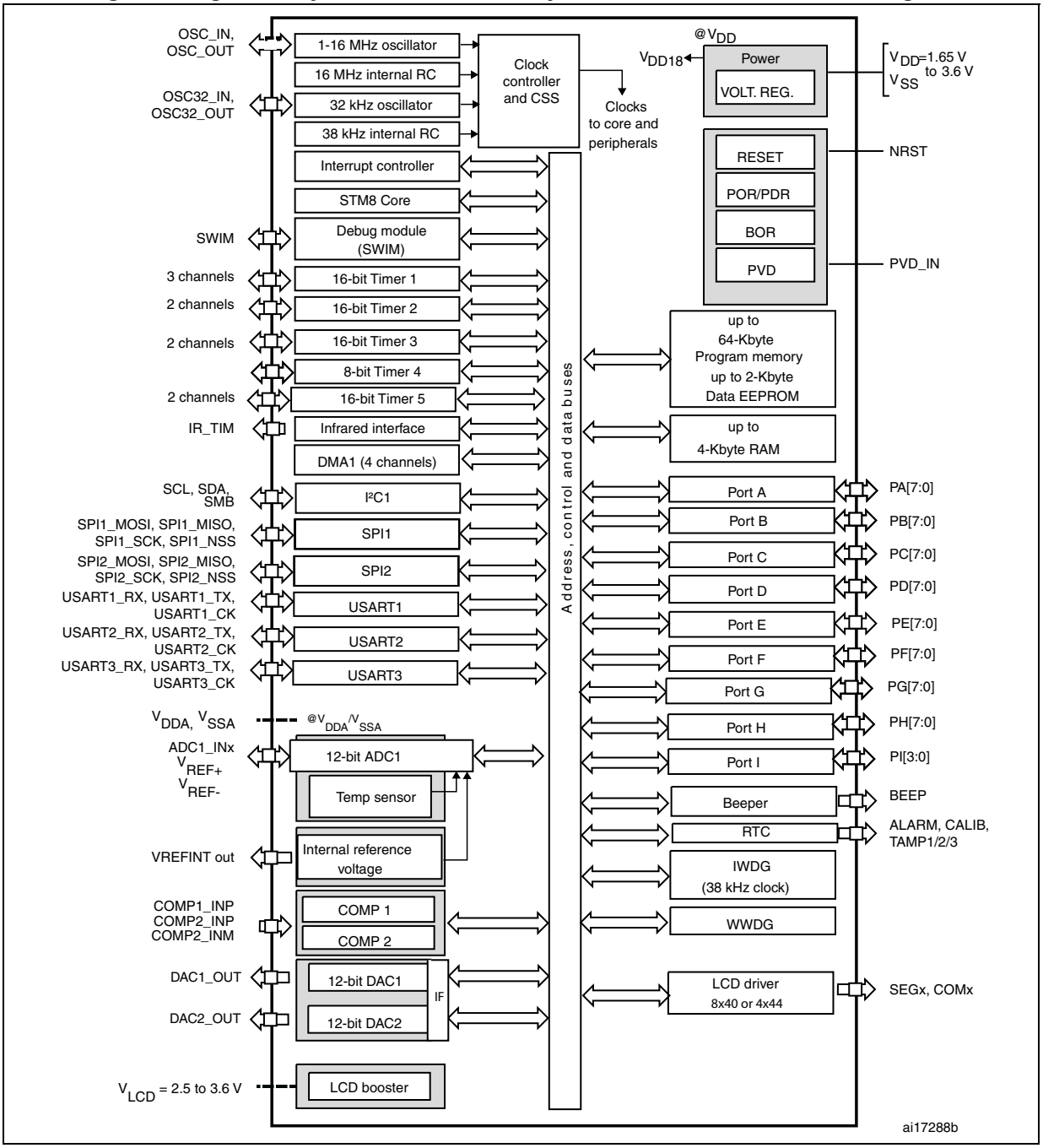
3 Functional overview

Figure 1. High-density and medium+ density STM8L15xx6/8 device block diagram



1. **Legend**:
   AF: alternate function
   ADC: Analog-to-digital converter
   BOR: Brownout reset
   DMA: Direct memory access
   DAC: Digital-to-analog converter
   I²C: Inter-integrated circuit multimaster interface
   IWDG: Independent watchdog

3.3 Reset and supply management

3.3.1 Power supply scheme

The device requires a 1.65 V to 3.6 V operating supply voltage (V_{DD}). The external power supply pins must be connected as follows:

- V_{SS1}, V_{DD1}, V_{SS2}, V_{DD2}, V_{SS3}, V_{DD3}, V_{SS4}, V_{DD4}= 1.65 to 3.6 V: external power supply for I/Os and for the internal regulator. Provided externally through V_{DD} pins, the corresponding ground pin is V_{SS}. V_{SS1}/V_{SS2}/V_{SS3}/V_{SS4} and V_{DD1}/V_{DD2}/V_{DD3}/V_{DD4} must not be left unconnected.
- V_{SSA}, V_{DDA} = 1.65 to 3.6 V: external power supplies for analog peripherals (minimum voltage to be applied to V_{DDA} is 1.8 V when the ADC1 is used). V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS}, respectively.
- V_{REF+}, V_{REF-} (for ADC1): external reference voltage for ADC1. Must be provided externally through V_{REF+} and V_{REF-} pin.
- V_{REF+} (for DAC1/2): external voltage reference for DAC1 and DAC2 must be provided externally through V_{REF+}.

3.3.2 Power supply supervisor

The device has an integrated ZEROPOWER power-on reset (POR)/power-down reset (PDR). For the device sales types without the “D” option (see *Section 11: Ordering information scheme*), it is coupled with a brownout reset (BOR) circuitry. It that case the device operates between 1.8 and 3.6 V, BOR is always active and ensures proper operation starting from 1.8 V. After the 1.8 V BOR threshold is reached, the option byte loading process starts, either to confirm or modify default thresholds, or to disable BOR permanently (in which case, the V_{DD} min. value at power-down is 1.65 V).

Five BOR thresholds are available through option bytes, starting from 1.8 V to 3 V. To reduce the power consumption in Halt mode, it is possible to automatically switch off the internal reference voltage (and consequently the BOR) in Halt mode. The device remains in reset state when V_{DD} is below a specified threshold, $V_{POR/PDR}$ or V_{BOR}, without the need for any external reset circuit.

Note: For device sales types with the “D” option (see Section 11: Ordering information scheme) BOR is permanently disabled and the device operates between 1.65 and 3.6 V. In this case it is not possible to enable BOR through the option bytes.

The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD}/V_{DDA} power supply and compares it to the V_{PVD} threshold. This PVD offers 7 different levels between 1.85 V and 3.05 V, chosen by software, with a step around 200 mV. An interrupt can be generated when V_{DD}/V_{DDA} drops below the V_{PVD} threshold and/or when V_{DD}/V_{DDA} is higher than the V_{PVD} threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5084	Reserved area (1 byte)			
0x00 5085	DMA1	DMA1_C1M0ARH	DMA1 memory 0 address high register (channel 1)	0x00
0x00 5086		DMA1_C1M0ARL	DMA1 memory 0 address low register (channel 1)	0x00
0x00 5087 0x00 5088	Reserved area (2 byte)			
0x00 5089	DMA1	DMA1_C2CR	DMA1 channel 2 configuration register	0x00
0x00 508A		DMA1_C2SPR	DMA1 channel 2 status & priority register	0x00
0x00 508B		DMA1_C2NDTR	DMA1 number of data to transfer register (channel 2)	0x00
0x00 508C		DMA1_C2PARH	DMA1 peripheral address high register (channel 2)	0x52
0x00 508D		DMA1_C2PARL	DMA1 peripheral address low register (channel 2)	0x00
0x00 508E	Reserved area (1 byte)			
0x00 508F		DMA1_C2M0ARH	DMA1 memory 0 address high register (channel 2)	0x00
0x00 5090		DMA1_C2M0ARL	DMA1 memory 0 address low register (channel 2)	0x00
0x00 5091 0x00 5092	Reserved area (2 byte)			
0x00 5093	DMA1	DMA1_C3CR	DMA1 channel 3 configuration register	0x00
0x00 5094		DMA1_C3SPR	DMA1 channel 3 status & priority register	0x00
0x00 5095		DMA1_C3NDTR	DMA1 number of data to transfer register (channel 3)	0x00
0x00 5096		DMA1_C3PARH_ C3M1ARH	DMA1 peripheral address high register (channel 3)	0x40
0x00 5097		DMA1_C3PARL_ C3M1ARL	DMA1 peripheral address low register (channel 3)	0x00
0x00 5098		DMA_C3M0EAR	DMA channel 3 memory 0 extended address register	0x00
0x00 5099		DMA1_C3M0ARH	DMA1 memory 0 address high register (channel 3)	0x00
0x00 509A		DMA1_C3M0ARL	DMA1 memory 0 address low register (channel 3)	0x00
0x00 509B to 0x00 509C	Reserved area (3 byte)			

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5262	TIM2	TIM2_CCR1L	TIM2 capture/compare register 1 low	0x00
0x00 5263		TIM2_CCR2H	TIM2 capture/compare register 2 high	0x00
0x00 5264		TIM2_CCR2L	TIM2 capture/compare register 2 low	0x00
0x00 5265		TIM2_BKR	TIM2 break register	0x00
0x00 5266		TIM2_OISR	TIM2 output idle state register	0x00
0x00 5267 to 0x00 527F	Reserved area (25 byte)			
0x00 5280	TIM3	TIM3_CR1	TIM3 control register 1	0x00
0x00 5281		TIM3_CR2	TIM3 control register 2	0x00
0x00 5282		TIM3_SMCR	TIM3 Slave mode control register	0x00
0x00 5283		TIM3_ETR	TIM3 external trigger register	0x00
0x00 5284		TIM3_DER	TIM3 DMA1 request enable register	0x00
0x00 5285		TIM3_IER	TIM3 interrupt enable register	0x00
0x00 5286		TIM3_SR1	TIM3 status register 1	0x00
0x00 5287		TIM3_SR2	TIM3 status register 2	0x00
0x00 5288		TIM3_EGR	TIM3 event generation register	0x00
0x00 5289		TIM3_CCMR1	TIM3 Capture/Compare mode register 1	0x00
0x00 528A		TIM3_CCMR2	TIM3 Capture/Compare mode register 2	0x00
0x00 528B		TIM3_CCER1	TIM3 Capture/Compare enable register 1	0x00
0x00 528C		TIM3_CNTRH	TIM3 counter high	0x00
0x00 528D		TIM3_CNTRL	TIM3 counter low	0x00
0x00 528E		TIM3_PSCR	TIM3 prescaler register	0x00
0x00 528F		TIM3_ARRH	TIM3 Auto-reload register high	0xFF
0x00 5290		TIM3_ARRL	TIM3 Auto-reload register low	0xFF
0x00 5291		TIM3_CCR1H	TIM3 Capture/Compare register 1 high	0x00
0x00 5292		TIM3_CCR1L	TIM3 Capture/Compare register 1 low	0x00
0x00 5293		TIM3_CCR2H	TIM3 Capture/Compare register 2 high	0x00
0x00 5294		TIM3_CCR2L	TIM3 Capture/Compare register 2 low	0x00
0x00 5295		TIM3_BKR	TIM3 break register	0x00
0x00 5296		TIM3_OISR	TIM3 output idle state register	0x00
0x00 5297 to 0x00 52AF	Reserved area (25 byte)			

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5310	TIM5	TIM5_ARRL	TIM5 Auto-reload register low	0xFF
0x00 5311		TIM5_CCR1H	TIM5 Capture/Compare register 1 high	0x00
0x00 5312		TIM5_CCR1L	TIM5 Capture/Compare register 1 low	0x00
0x00 5313		TIM5_CCR2H	TIM5 Capture/Compare register 2 high	0x00
0x00 5314		TIM5_CCR2L	TIM5 Capture/Compare register 2 low	0x00
0x00 5315		TIM5_BKR	TIM5 break register	0x00
0x00 5316		TIM5_OISR	TIM5 output idle state register	0x00
0x00 5317 to 0x00 533F	Reserved area			
0x00 5340	ADC1	ADC1_CR1	ADC1 configuration register 1	0x00
0x00 5341		ADC1_CR2	ADC1 configuration register 2	0x00
0x00 5342		ADC1_CR3	ADC1 configuration register 3	0x1F
0x00 5343		ADC1_SR	ADC1 status register	0x00
0x00 5344		ADC1_DRH	ADC1 data register high	0x00
0x00 5345		ADC1_DRL	ADC1 data register low	0x00
0x00 5346		ADC1_HTRH	ADC1 high threshold register high	0x0F
0x00 5347		ADC1_HTRL	ADC1 high threshold register low	0xFF
0x00 5348		ADC1_LTRH	ADC1 low threshold register high	0x00
0x00 5349		ADC1_LTRL	ADC1 low threshold register low	0x00
0x00 534A		ADC1_SQR1	ADC1 channel sequence 1 register	0x00
0x00 534B		ADC1_SQR2	ADC1 channel sequence 2 register	0x00
0x00 534C		ADC1_SQR3	ADC1 channel sequence 3 register	0x00
0x00 534D		ADC1_SQR4	ADC1 channel sequence 4 register	0x00
0x00 534E		ADC1_TRIGR1	ADC1 trigger disable 1	0x00
0x00 534F		ADC1_TRIGR2	ADC1 trigger disable 2	0x00
0x00 5350		ADC1_TRIGR3	ADC1 trigger disable 3	0x00
0x00 5351		ADC1_TRIGR4	ADC1 trigger disable 4	0x00
0x00 5352 to 0x00 537F	Reserved area (46 byte)			
0x00 5380	DAC	DAC_CH1CR1	DAC channel 1 control register 1	0x00
0x00 5381		DAC_CH1CR2	DAC channel 1 control register 2	0x00
0x00 5382		DAC_CH2CR1	DAC channel 2 control register 1	0x00
0x00 5383		DAC_CH2CR2	DAC channel 2 control register 2	0x00
0x00 5384		DAC_SWTRIG	DAC software trigger register	0x00
0x00 5385		DAC_SR	DAC status register	0x00

Table 9. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5422 to 0x00 542E	Reserved area			
0x00 542F	LCD	LCD_CR4	LCD control register 4	0x00
0x00 5430	RI	Reserved area (1 byte)		0x00
0x00 5431		RI_ICR1	Timer input capture routing register 1	0x00
0x00 5432		RI_ICR2	Timer input capture routing register 2	0x00
0x00 5433		RI_IOIR1	I/O input register 1	0xXX
0x00 5434		RI_IOIR2	I/O input register 2	0xXX
0x00 5435		RI_IOIR3	I/O input register 3	0xXX
0x00 5436		RI_IOCMR1	I/O control mode register 1	0x00
0x00 5437		RI_IOCMR2	I/O control mode register 2	0x00
0x00 5438		RI_IOCMR3	I/O control mode register 3	0x00
0x00 5439		RI_IOSR1	I/O switch register 1	0x00
0x00 543A		RI_IOSR2	I/O switch register 2	0x00
0x00 543B		RI_IOSR3	I/O switch register 3	0x00
0x00 543C		RI_IOGCR	I/O group control register	0x3F
0x00 543D		RI_ASCR1	Analog switch register 1	0x00
0x00 543E		RI_ASCR2	Analog switch register 2	0x00
0x00 543F		RI_RCR	Resistor control register 1	0x00
0x00 5440	COMP1/ COMP2	COMP_CSR1	Comparator control and status register 1	0x00
0x00 5441		COMP_CSR2	Comparator control and status register 2	0x00
0x00 5442		COMP_CSR3	Comparator control and status register 3	0x00
0x00 5443		COMP_CSR4	Comparator control and status register 4	0x00
0x00 5444		COMP_CSR5	Comparator control and status register 5	0x00

1. These registers are not impacted by a system reset. They are reset at power-on.

Table 10. CPU/SWIM/debug module/interrupt controller registers (continued)

Address	Block	Register label	Register name	Reset status
0x00 7F90	DM	DM_BK1RE	DM breakpoint 1 register extended byte	0xFF
0x00 7F91		DM_BK1RH	DM breakpoint 1 register high byte	0xFF
0x00 7F92		DM_BK1RL	DM breakpoint 1 register low byte	0xFF
0x00 7F93		DM_BK2RE	DM breakpoint 2 register extended byte	0xFF
0x00 7F94		DM_BK2RH	DM breakpoint 2 register high byte	0xFF
0x00 7F95		DM_BK2RL	DM breakpoint 2 register low byte	0xFF
0x00 7F96		DM_CR1	DM Debug module control register 1	0x00
0x00 7F97		DM_CR2	DM Debug module control register 2	0x00
0x00 7F98		DM_CSR1	DM Debug module control/status register 1	0x10
0x00 7F99		DM_CSR2	DM Debug module control/status register 2	0x00
0x00 7F9A		DM_ENFCTR	DM enable function register	0xFF
0x00 7F9B to 0x00 7F9F	Reserved area (5 byte)			

1. Accessible by debug module only

Table 13. Option byte description

Option byte no.	Option description
OPT0	**ROP[7:0]** Memory readout protection (ROP) 0xAA: Disable readout protection (write access via SWIM protocol) Refer to Readout protection section in the STM8L reference manual (RM0031).
OPT1	**UBC[7:0]** Size of the user boot code area UBC[7:0] Size of the user boot code area 0x00: No UBC 0x01: Page 0 reserved for the UBC and write protected. ... 0xFF: Page 0 to 254 reserved for the UBC and write-protected. Refer to User boot code section in the STM8L reference manual (RM0031).
OPT2	**PCODESIZE[7:0]** Size of the proprietary code area 0x00: No proprietary code area 0x01: Page 0 reserved for the proprietary code and read/write protected. ... 0xFF: Page 0 to 254 reserved for the proprietary code and read/write protected. Refer to Proprietary code area (PCODE) section in the STM8L reference manual (RM0031) for more details.
OPT3	**IWDG_HW:** Independent watchdog 0: Independent watchdog activated by software 1: Independent watchdog activated by hardware
	IWDG_HALT: Independent watchdog off in Halt/Active-halt 0: Independent watchdog continues running in Halt/Active-halt mode 1: Independent watchdog stopped in Halt/Active-halt mode
	WWDG_HW: Window watchdog 0: Window watchdog activated by software 1: Window watchdog activated by hardware
	WWDG_HALT: Window window watchdog reset on Halt/Active-halt 0: Window watchdog stopped in Halt mode 1: Window watchdog generates a reset when MCU enters Halt mode
OPT4	**HSECNT**: Number of HSE oscillator stabilization clock cycles 0x00 - 1 clock cycle 0x01 - 16 clock cycles 0x10 - 512 clock cycles 0x11 - 4096 clock cycles
	LSECNT: Number of LSE oscillator stabilization clock cycles 0x00 - 1 clock cycle 0x01 - 16 clock cycles 0x10 - 512 clock cycles 0x11 - 4096 clock cycles

9.3.3 Supply current characteristics

Total current consumption

The MCU is placed under the following conditions:

- All I/O pins in input mode with a static value at V_{DD} or V_{SS} (no load)
- All peripherals are disabled except if explicitly mentioned.

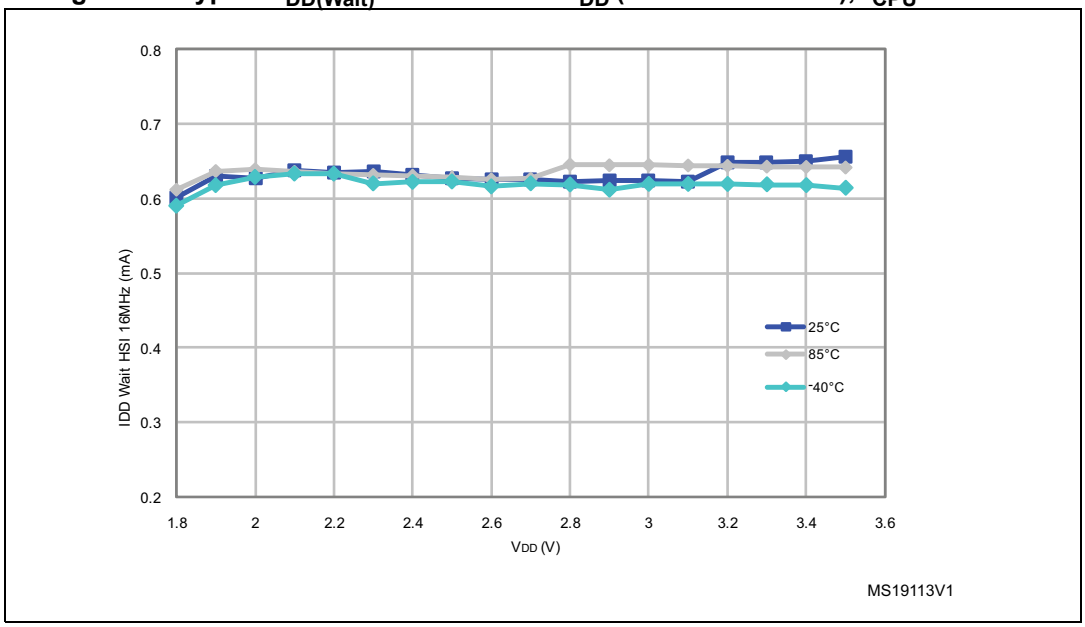
In the following table, data are based on characterization results, unless otherwise specified.

Subject to general operating conditions for V_{DD} and T_A.

Table 20. Total current consumption in Run mode

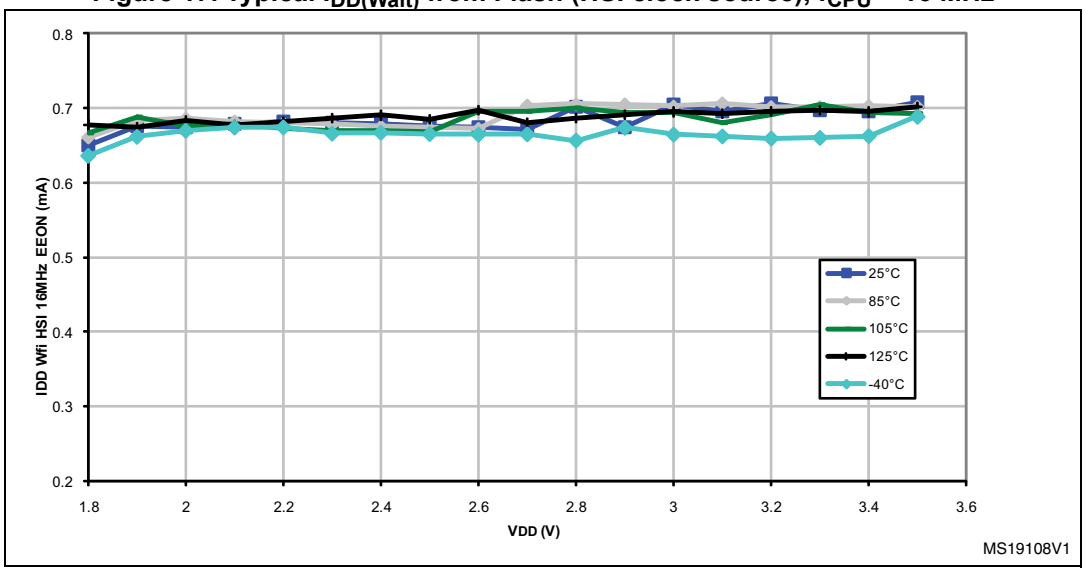
Symbol	Para meter	Conditions(1)			Typ.	Max.				Unit
						55°C	85 °C (2)	105 °C (3)	125 °C (4)	
$I_{DD(RUN)}$	Supply current in run mode (5)	All peripherals OFF, code executed from RAM, V_{DD} from 1.65 V to 3.6 V	HSI RC osc. (16 MHz)(6)	f_{CPU} = 125 kHz	0.22	0.28	0.39	0.47	0.51	mA
				f_{CPU} = 1 MHz	0.32	0.38	0.49	0.57	0.61	
				f_{CPU} = 4 MHz	0.59	0.65	0.76	0.84	0.88	
				f_{CPU} = 8 MHz	0.93	0.99	1.1	1.18	1.22	
				f_{CPU} = 16 MHz	1.62	1.68	1.79(7)	1.87(7)	1.91(7)	
			HSE external clock (f_{CPU}=f_{HSE}) (8)	f_{CPU} = 125 kHz	0.21	0.25	0.35	0.44	0.49	
				f_{CPU} = 1 MHz	0.3	0.34	0.44	0.53	0.58	
				f_{CPU} = 4 MHz	0.57	0.61	0.71	0.8	0.85	
				f_{CPU} = 8 MHz	0.95	0.99	1.09	1.18	1.23	
				f_{CPU} = 16 MHz	1.73	1.77	1.87(7)	1.96(7)	2.01(7)	
			LSI RC osc. (typ. 38 kHz)	f_{CPU} = f_{LSI}	0.029	0.035	0.039	0.044	0.055	
			LSE external clock (32.768 kHz)	f_{CPU} = f_{LSE}	0.028	0.034	0.038	0.042	0.054	

Figure 16. Typical $I_{DD(Wait)}$ from RAM vs. V_{DD} (HSI clock source), f_{CPU} = 16 MHz



1. Typical current consumption measured with code executed from RAM.

Figure 17. Typical $I_{DD(Wait)}$ from Flash (HSI clock source), f_{CPU} = 16 MHz



1. Typical current consumption measured with code executed from Flash.

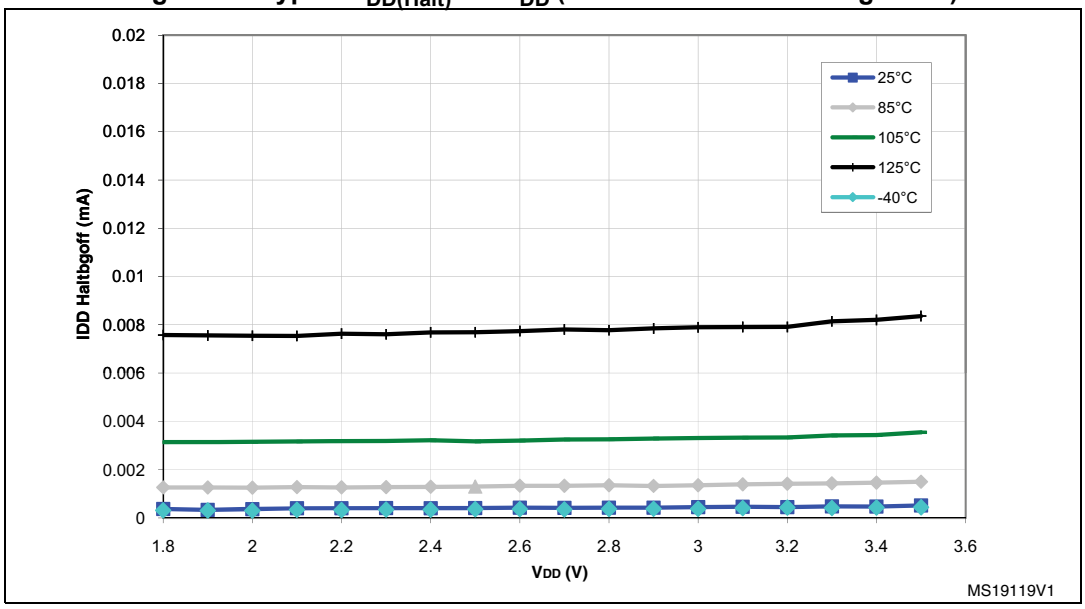
In the following table, data are based on characterization results, unless otherwise specified.

Table 26. Total current consumption and timing in Halt mode at V_{DD} = 1.65 to 3.6 V

Symbol	Parameter	Condition(1)	Typ.	Max.	Unit
$I_{DD(Halt)}$	Supply current in Halt mode (Ultra-low-power ULP bit =1 in the PWR_CSR2 register)	T_A = -40 °C to 25 °C	400	1600(2)	nA
		T_A = 55 °C	810	2400	
		T_A = 85 °C	1600	4500(2)	
		T_A = 105 °C	2900	7700(2)	
		T_A = 125 °C	5.6	18(2)	µA
$I_{DD(WUHalt)}$	Supply current during wakeup time from Halt mode (using HSI)		2.4		mA
$t_{WU\_HSI(Halt)}$(3)(4)	Wakeup time from Halt to Run mode (using HSI)		4.7	7	µs
$t_{WU\_LSI(Halt)}$(3)(4)	Wakeup time from Halt mode to Run mode (using LSI)		150		µs

1. T_A = -40 to 125 °C, no floating I/O, unless otherwise specified
2. Tested in production
3. ULP=0 or ULP=1 and FWU=1 in the PWR_CSR2 register
4. Wakeup time until start of interrupt vector fetch.
   The first word of interrupt routine is fetched 4 CPU cycles after t_{WU}

Figure 21. Typical $I_{DD(Halt)}$ vs. V_{DD} (internal reference voltage OFF)



9.3.6 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below V_{SS} or above V_{DD} (for standard pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error, out of spec current injection on adjacent pins or other functional failure (for example reset, oscillator frequency deviation, LCD levels, etc.).

The test results are given in the following table.

Table 37. I/O current injection susceptibility

Symbol	Description	Functional susceptibility		Unit
		Negative injection	Positive injection	
I_{INJ}	Injected current on true open-drain pins	-5	+0	mA
	Injected current on all 5 V tolerant (FT) pins	-5	+0	
	Injected current on any other pin	-5	+5	

9.3.7 I/O port pin characteristics

General characteristics

Subject to general operating conditions for V_{DD} and T_A unless otherwise specified. All unused pins must be kept at a fixed voltage: using the output mode of the I/O for example or an external pull-up or pull-down resistor.

9.3.9 LCD controller (STM8L152x6/8 only)

In the following table, data are guaranteed by design.

Table 45. LCD characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{LCD}	LCD external voltage	-		3.6	V
V_{LCD0}	LCD internal reference voltage 0	-	2.6	-	
V_{LCD1}	LCD internal reference voltage 1	-	2.7	-	
V_{LCD2}	LCD internal reference voltage 2	-	2.8	-	
V_{LCD3}	LCD internal reference voltage 3	-	3.0	-	
V_{LCD4}	LCD internal reference voltage 4	-	3.1	-	
V_{LCD5}	LCD internal reference voltage 5	-	3.2	-	
V_{LCD6}	LCD internal reference voltage 6	-	3.4	-	
V_{LCD7}	LCD internal reference voltage 7	-	3.5	-	
C_{EXT}	V_{LCD} external capacitance	0.1	1	2	µF
I_{DD}	Supply current(1) at V_{DD} = 1.8 V	-	3	-	µA
	Supply current(1) at V_{DD} = 3 V	-	3	-	
R_{HN}(2)	High value resistive network (low drive)	-	6.6	-	MΩ
R_{LN}(3)	Low value resistive network (high drive)	-	240	-	kΩ
V_{33}	Segment/Common higher level voltage	-		V_{LCDx}	V
V_{34}	Segment/Common 3/4 level voltage	-	$3/4V_{LCDx}$	-	
V_{23}	Segment/Common 2/3 level voltage	-	$2/3V_{LCDx}$	-	
V_{12}	Segment/Common 1/2 level voltage	-	$1/2V_{LCDx}$	-	
V_{13}	Segment/Common 1/3 level voltage	-	$1/3V_{LCDx}$	-	
V_{14}	Segment/Common 1/4 level voltage	-	$1/4V_{LCDx}$	-	
V_0	Segment/Common lowest level voltage	0	-	-	

1. LCD enabled with 3 V internal booster (LCD_CR1 = 0x08), 1/4 duty, 1/3 bias, division ratio= 64, all pixels active, no LCD connected.
2. R_{HN} is the total high value resistive network.
3. R_{LN} is the total low value resistive network.

VLCD external capacitor (STM8L152x6/8 only)

The application can achieve a stabilized LCD reference voltage by connecting an external capacitor C_{EXT} to the V_{LCD} pin. C_{EXT} is specified in *Table 45*.

9.3.10 Embedded reference voltage

In the following table, data are based on characterization results unless otherwise specified.

Table 46. Reference voltage characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_{REFINT}	Internal reference voltage consumption	-	-	1.4		µA
$T_{S\_VREFINT}$(1)(2)	ADC sampling time when reading the internal reference voltage	-	-	5	10	µs
I_{BUF}(1)	Internal reference voltage buffer consumption (used for ADC)	-	-	13.5	25	µA
$V_{REFINT\ out}$	Reference voltage output	-	1.202 (3)	1.224	1.242 (3)	V
I_{LPBUF}(1)	Internal reference voltage low-power buffer consumption (used for comparators or output)	-	-	730	1200	nA
I_{REFOUT}(1)(4)	Buffer output current	-	-		1	µA
C_{REFOUT}	Reference voltage output load	-	-		50	pF
$t_{VREFINT}$(1)	Internal reference voltage startup time	-	-	2	3	ms
t_{BUFEN}(1)(2)	Internal reference voltage buffer startup time once enabled	-	-		10	µs
$ACC_{VREFINT}$(5)	Accuracy of V_{REFINT} stored in the VREFINT_Factory_CONV byte	-	-		± 5	mV
$STAB_{VREFINT}$	Stability of V_{REFINT} over temperature	-40 °C ≤T_A ≤ 125 °C	-	20	50	ppm/°C
	Stability of V_{REFINT} over temperature	0 °C ≤T_A ≤ 50 °C	-	-	20	ppm/°C
$STAB_{VREFINT}$	Stability of V_{REFINT} after 1000 hours	-	-	-	1000	ppm

1. Guaranteed by design.
2. Defined when ADC output reaches its final value ±1/2LSB
3. Tested in production at V_{DD} = 3 V ±10 mV.
4. To guarantee less than 1% V_{REFOUT} deviation
5. Measured at V_{DD} = 3 V ±10 mV. This value takes into account V_{DD} accuracy and ADC conversion accuracy.

9.3.15 EMC characteristics

Susceptibility tests are performed on a sample basis during product characterization.

Functional EMS (electromagnetic susceptibility)

Based on a simple running application on the product (toggling 2 LEDs through I/O ports), the product is stressed by two electromagnetic events until a failure occurs (indicated by the LEDs).

- **ESD**: Electrostatic discharge (positive and negative) is applied on all pins of the device until a functional disturbance occurs. This test conforms with the IEC 61000 standard.
- **FTB**: A burst of fast transient voltage (positive and negative) is applied to V_{DD} and V_{SS} through a 100 pF capacitor, until a functional disturbance occurs. This test conforms with the IEC 61000 standard.

A device reset allows normal operations to be resumed. The test results are given in the table below based on the EMS levels and classes defined in application note AN1709.

Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

Prequalification trials:

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

Table 58. EMS data

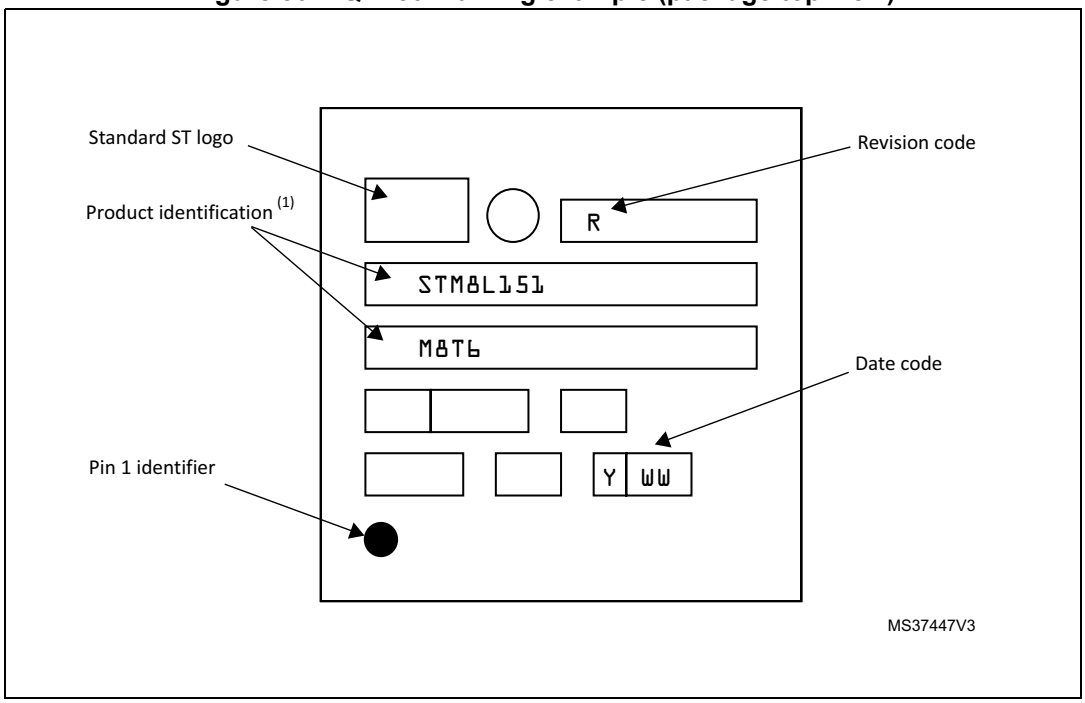
Symbol	Parameter	Conditions		Level/ Class
V_{FESD}	Voltage limits to be applied on any I/O pin to induce a functional disturbance	V_{DD} = 3.3 V, T_A = +25 °C, f_{CPU}= 16 MHz, conforms to IEC 61000		2B
V_{EFTB}	Fast transient voltage burst limits to be applied through 100 pF on V_{DD} and V_{SS} pins to induce a functional disturbance	V_{DD} = 3.3 V, T_A = +25 °C, f_{CPU} = 16 MHz, conforms to IEC 61000	Using HSI	4A
			Using HSE	2B

Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

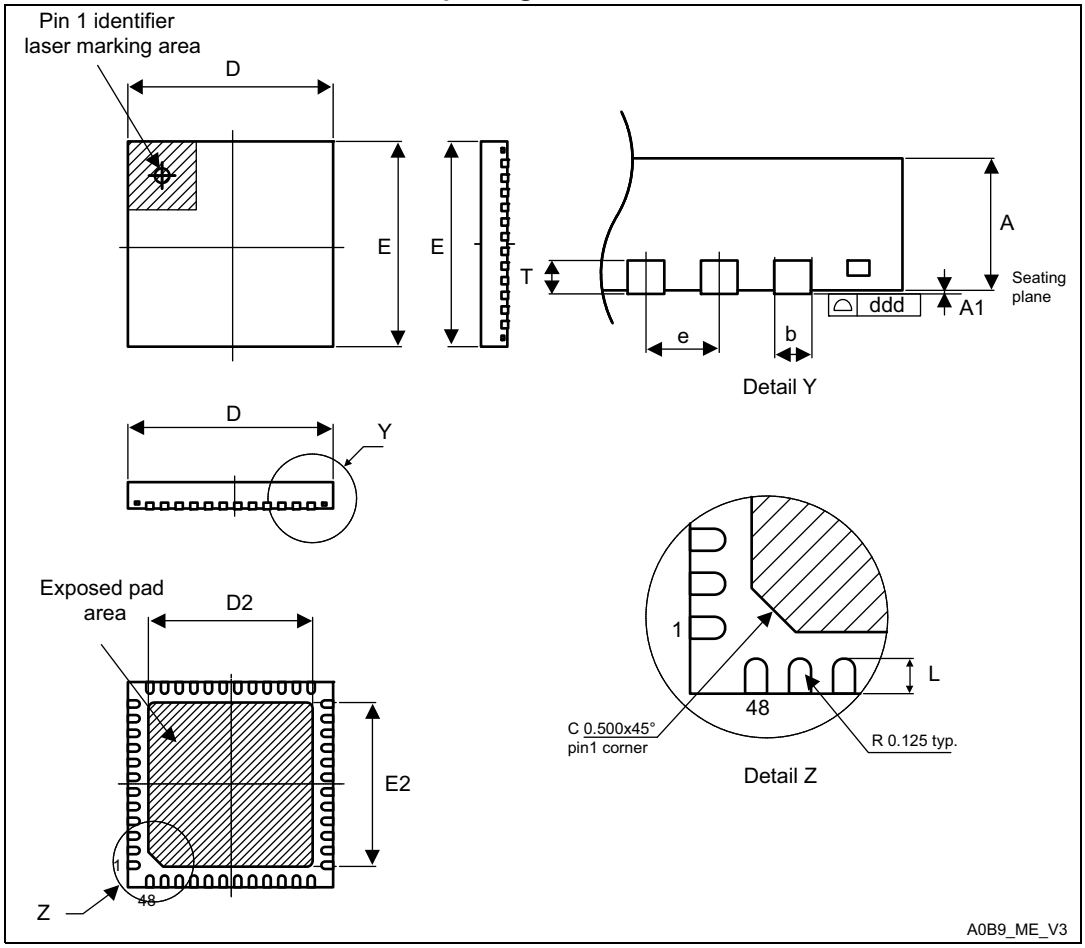
Figure 50. LQFP80 marking example (package top view)



1. Parts marked as “ES”,”E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

10.4 UFQFPN48 package information

Figure 57. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package outline



1. Drawing is not to scale.
2. All leads/pads should also be soldered to the PCB to improve the lead/pad solder joint life.
3. There is an exposed die pad on the underside of the UFQFPN package. It is recommended to connect and solder this back-side pad to PCB ground.